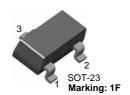


MMBT5550 NPN General Purpose Amplifier

• This device is designed for general purpose high voltage amplifiers and gas discharge display drivers.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings * T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	140	V
V _{CBO}	Collector-Base Voltage	160	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I _C	Collector current - Continuous	600	mA
T _J , T _{stg}	Junction and Storage Temperature	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics T_a = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units		
Off Charact	Off Characteristics						
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	$I_C = 1.0 \text{mA}, I_B = 0$	140		V		
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	160		V		
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \text{mA}, I_C = 0$	6.0		V		
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V, I _E = 0 V _{CB} = 100V, I _E = 0, T _a = 100°C		100 100	nA μA		
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 4.0V, I_{C} = 0$		50	nA		
On Charact	eristics						
h _{FE}	DC Current Gain	$I_{C} = 1.0$ mA, $V_{CE} = 5.0$ V $I_{C} = 10$ mA, $V_{CE} = 5.0$ V $I_{C} = 5$ 0mA, $V_{CE} = 5.0$ V	60 60 20	250			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA		0.15 0.25	V V		
V _{BE(sat)}	Base-Emitter On Voltage	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA		1.0 1.2	V V		

^{1.} These ratings are based on a maximum junction temperature of 150 degrees $\ensuremath{\text{C}}$.

^{2.} These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units	
Small Signa	Small Signal Characteristics					
f _T	Current Gain Bandwidth Product	I _C = 10mA, V _{CE} = 10V, f = 100MHz	50		MHz	
C _{obo}	Output Capacitance	V _{CB} = 10V, I _E = 0, f = 1.0MHz		6.0	pF	
C _{ibo}	Input Capacitance	$V_{BE} = 0.5V, I_{C} = 0, f = 1.0MHz$		30	pF	

Thermal Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P_{D}	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

^{*} Device mounted on FR-4 PCB 1.6" × 1.6" × 0.06."

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
1F	MMBT5550	SOT-23	7"		3,000

Typical Performance Characteristics

Figure 1. Typical Pulsed Current Gain vs Collector Current

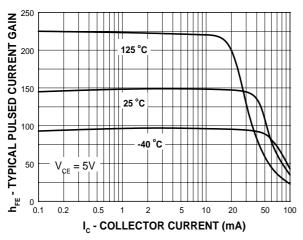


Figure 3. Base-Emitter Saturation Voltage vs Collector Current

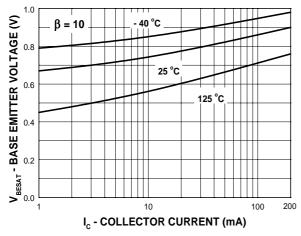


Figure 5. Collector Cutoff Current vs Ambient Temperature

MMBT5550 Rev. A

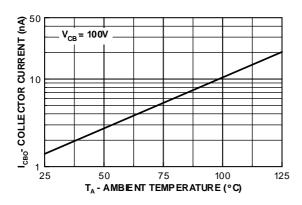


Figure 2. Collector-Emitter Saturation Voltage vs Collector Current

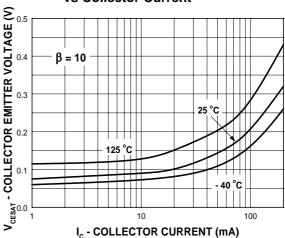


Figure 4. Base-Emitter On Voltage vs Collector Current

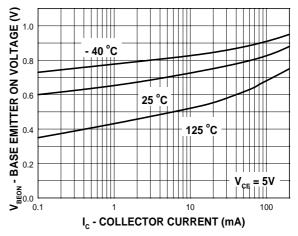
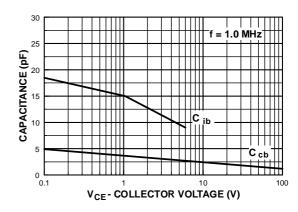
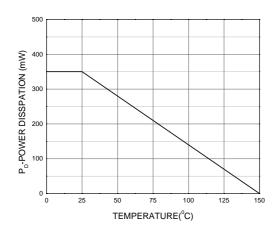


Figure 6. Input and Output Capacitance vs Reverse Voltaget



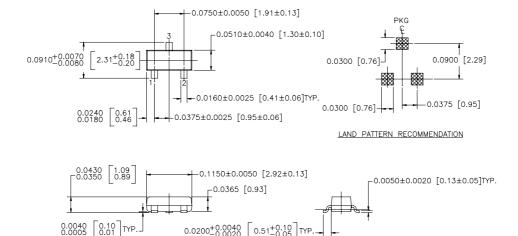
Typical Performance Characteristics (Continued)

Figure 7. Power Dissipation vs Ambient Temperature



Mechanical Dimensions

SOT-23



SOT 23, 3 LEADS LOW PROFILE

NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

Dimensions in Millimeters

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